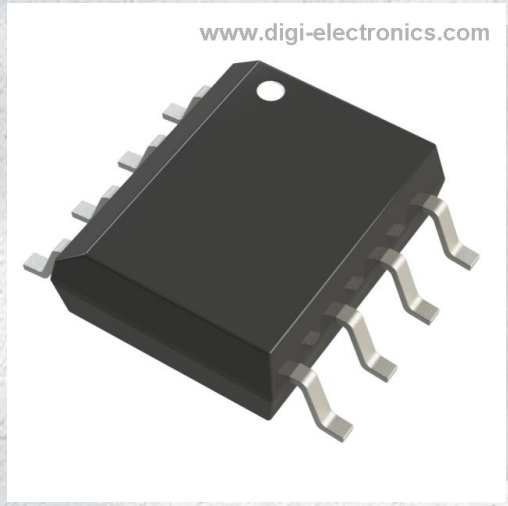
ZXMS6005DN8-13 Datasheet



DiGi Electronics Part Number	ZXMS6005DN8-13-DG
Manufacturer	Diodes Incorporated
Manufacturer Product Number	ZXMS6005DN8-13
Description	IC PWR DRIVER N-CHAN 1:1 8SOIC
Detailed Description	Power Switch/Driver 1:1 N-Channel 1.8A 8-SOIC

https://www.DiGi-Electronics.com

Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
ZXMS6005DN8-13	Diodes Incorporated
Series:	Product Status:
INTELLIFET®	Active
Switch Type:	Number of Outputs:
General Purpose	2
Ratio - Input:Output:	Output Configuration:
1:1	Low Side
Output Type:	Interface:
N-Channel	On/Off
Voltage - Load:	Voltage - Supply (Vcc/Vdd):
60V (Max)	3.3V, 5V
Current - Output (Max):	Rds On (Typ):
1.8A	150mOhm
Input Type:	Features:
Non-Inverting	Auto Restart
Fault Protection:	Operating Temperature:
Current Limiting (Fixed), Over Temperature, Over Voltage	-40°C ~ 125°C (TA)
Mounting Type:	Supplier Device Package:
Surface Mount	8-SOIC
Package / Case:	Base Product Number:
8-SOIC (0.154", 3.90mm Width)	ZXMS6005

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8542.39.0001	

Lead-Free Green

ZXMS6005DN8

60V N-CHANNEL SELF PROTECTED ENHANCEMENT MODE IntelliFET MOSFET

Product Summary

- Continous Drain-Source Voltage: 60V
- On-State Resistance: 200mΩ
- Nominal Load Current (V_{IN} = 5V): 1.8A
- Clamping Energy: 120mJ

Description

The ZXMS6005DN8 is a dual self-protected low-side IntelliFET™ MOSFET with logic level input. It integrates over-temperature, overcurrent, overvoltage (active clamp) and ESD protected logic level functionality. The ZXMS6005DN8 is ideal as a general purpose switch driven from 3.3V or 5V microcontrollers in harsh environments where standard MOSFETs are not rugged enough.

Applications

- Lamp Driver
- Motor Driver
- Relay Driver
- Solenoid Driver

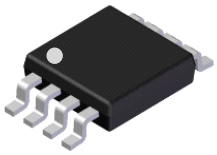
Features and Benefits

- Low Input Current
- Logic Level Input (3.3V and 5V)
- Short Circuit Protection with Auto Restart
- Overvoltage Protection (Active Clamp)
- Thermal Shutdown with Auto Restart
- Overcurrent Protection
- Input Protection (ESD)
- High Continuous Current Rating
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **An Automotive-Compliant Part is Available Under Separate Datasheet (ZXMS6005DN8Q)**

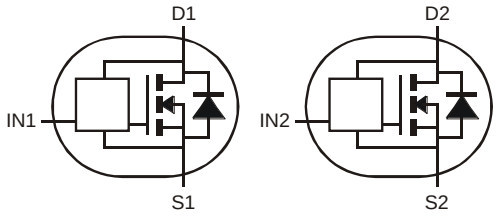
Mechanical Data

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish e3
- Weight: 79.1mg (Approximate)

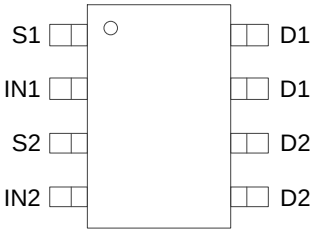
SO-8



Top View



Device Symbol



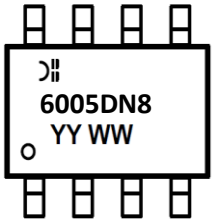
Top View
Pin-Out

Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
ZXMS6005DN8-13	6005DN8	13	12	2,500 units

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

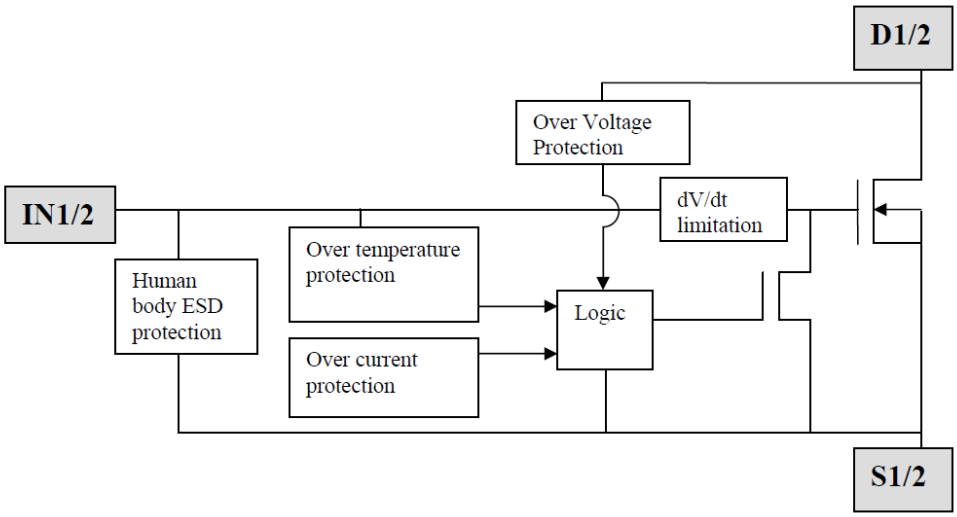


Top View

= Manufacturer's Marking
6005DN8 = Product Type Marking Code
YYWW = Date Code Marking
YY: Year
WW: Week: 01~52;
52 represents 52 and 53 week

IntelliFET is a trademark of Diodes Incorporated.

Functional Block Diagram



Application Information

- Two Completely Isolated Independent Channels
- Especially Suited for Loads with a High In-rush Current Such as Lamps and Motors
- All Types of Resistive, Inductive and Capacitive Loads in Switching Applications
- µC Compatible Power Switch for 12V and 24V DC Applications
- Replaces Electromechanical Relays and Discrete Circuits
- Linear Mode Capability — the current-limiting protection circuitry is designed to deactivate at low V_{DS} to minimize on-state power dissipation. The maximum DC operating current is therefore determined by the thermal capability of the package or board combination, rather than by the protection circuitry. This does not compromise the product's ability to self-protect at low V_{DS}

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise stated.)

Characteristic	Symbol	Value	Unit
Continuous Drain-Source Voltage	V_{DS}	60	V
Drain-Source Voltage For Short Circuit Protection	$V_{DS(SC)}$	16	V
Continuous Input Voltage	V_{IN}	-0.5 to +6	V
Continuous Input Current @-0.2V ≤ V_{IN} ≤ 6V Continuous Input Current @V_{IN} < -0.2V or V_{IN} > 6V	I_{IN}	No limit $\lvert I_{IN} \rvert \le 2$	mA
Pulsed Drain Current @V_{IN} = 3.3V	I_{DM}	5	A
Pulsed Drain Current @V_{IN} = 5V	I_{DM}	6	A
Continuous Source Current (Body Diode) (Note 5)	I_S	2.5	A
Pulsed Source Current (Body Diode)	I_{SM}	10	A
Unclamped Single Pulse Inductive Energy, T_J = +25°C, I_D = 0.5A, V_{DD} = 24V	E_{AS}	120	mJ
Electrostatic Discharge (Human Body Model)	V_{HBM}	4,000	V
Charged Device Model	V_{CDM}	1,000	V

Note: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Recommended Operating Conditions

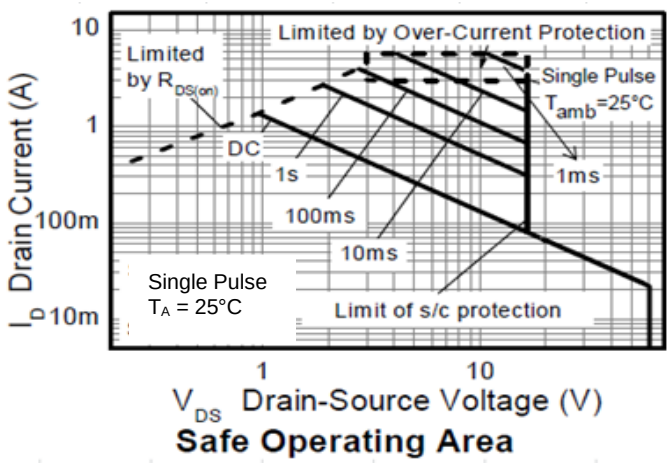
The ZXMS6005DN8 is optimized for use with µC operating from 3.3V and 5V supplies.

Characteristic	Symbol	Min	Max	Unit
Input Voltage Range	V_{IN}	0	5.5	V
Ambient Temperature Range	T_A	-40	+125	°C
High Level Input Voltage for MOSFET to be On	V_{IH}	3	5.5	V
Low Level Input Voltage for MOSFET to be Off	V_{IL}	0	0.7	V
Peripheral Supply Voltage (Voltage to which load is referred)	V_P	0	16	V

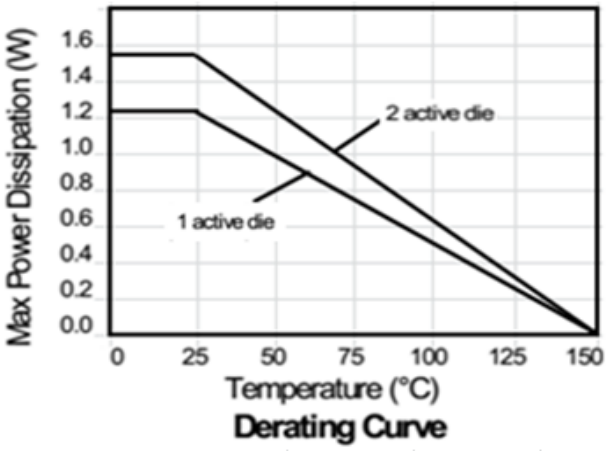
Thermal Characteristics (@T_A = +25°C, unless otherwise stated.)

Characteristic	Symbol	Value	Unit
Power Dissipation at T_A = +25°C (Note 5) Linear Derating Factor	P_D	1.21 9.7	W mW/°C
Power Dissipation at T_A = +25°C (Note 6) Linear Derating Factor	P_D	1.56 12.5	W mW/°C
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	103	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	$R_{\theta JA}$	81	°C/W
Thermal Resistance, Junction to Case (Note 7)	$R_{\theta JC}$	13.5	°C/W
Operating Temperature Range	T_J	-40 to +150	°C
Storage Temperature Range	T_{STG}	-55 to +150	°C

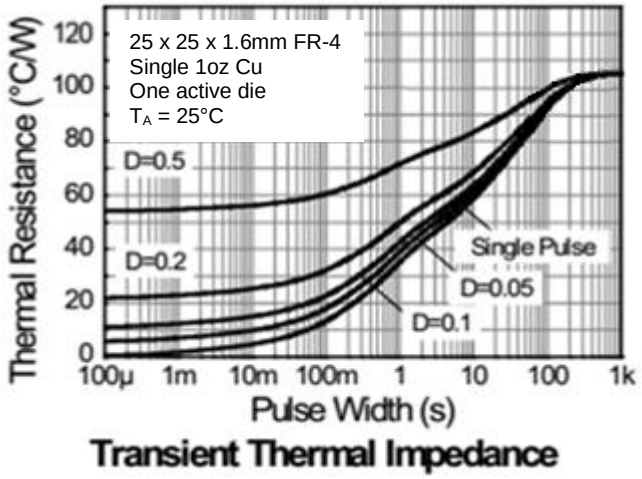
Notes: 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate.
7. Thermal resistance between junction and the mounting surfaces of drain and source pins.



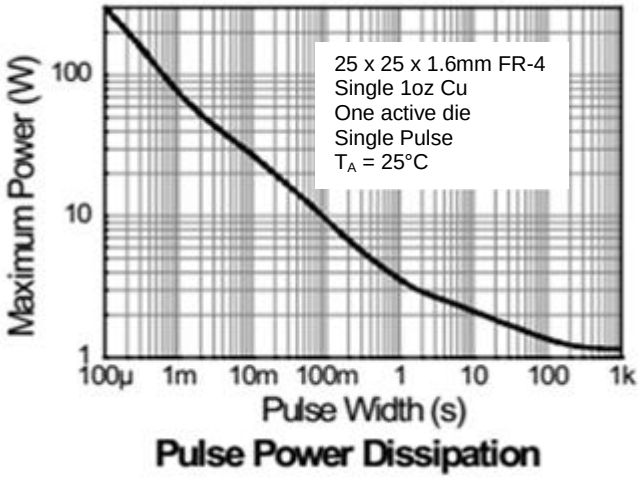
Safe Operating Area



Derating Curve



Transient Thermal Impedance



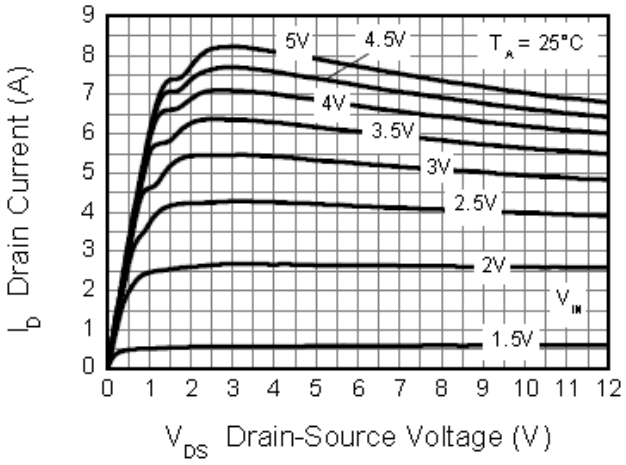
Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

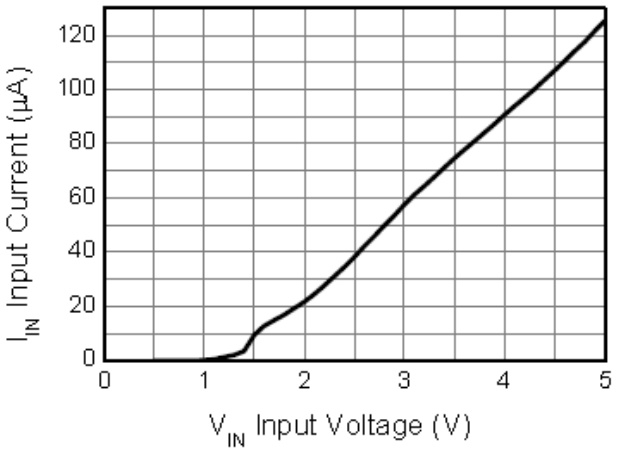
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Static Characteristics						
Drain-Source Clamp Voltage	$V_{DS(AZ)}$	60	65	70	V	I_D = 10mA
Off-State Drain Current	I_{DSS}	—	—	1	µA	V_{DS} = 12V, V_{IN} = 0V
		—	—	2		V_{DS} = 36V, V_{IN} = 0V
Input Threshold Voltage	$V_{IN(TH)}$	0.7	1	1.5	V	V_{DS} = V_{GS}, I_D = 1mA
Input Current	I_{IN}	—	60	100	µA	V_{IN} = 3V
		—	120	200		V_{IN} = 5V
Input Current while Over-Temperature Active	—	—	—	300	µA	V_{IN} = 5V
Static Drain-Source On-State Resistance	$R_{DS(ON)}$	—	170	250	mΩ	V_{IN} = 3V, I_D = 1A
		—	150	200		V_{IN} = 5V, I_D = 1A
Continuous Drain Current (Note 5)	I_D	1.4	—	—	A	V_{IN} = 3V; T_A = +25°C
		1.6	—	—		V_{IN} = 5V; T_A = +25°C
Continuous Drain Current (Note 6)		1.7	—	—		V_{IN} = 3V; T_A = +25°C
		1.8	—	—		V_{IN} = 5V; T_A = +25°C
Current Limit (Note 8)	$I_{D(LIM)}$	2.2	5	—	A	V_{IN} = 3V
		3.3	7	—		V_{IN} = 5V
Dynamic Characteristics						
Turn On Delay Time	$t_{D(ON)}$	—	6	—	µs	V_{DD} = 12V, I_D = 0.5A, V_{GS} = 5V
Rise Time	t_R	—	14	—	µs	
Turn Off Delay Time	$t_{D(OFF)}$	—	34	—	µs	
Fall Time	t_F	—	19	—	µs	
Over-Temperature Protection						
Thermal Overload Trip Temperature (Note 9)	T_{JT}	+150	+175	—	°C	—
Thermal Hysteresis (Note 9)	ΔT_{JT}	—	+10	—	°C	—

Notes:
8. The drain current is restricted only when the device is in saturation (see graph “Typical Output Characteristic”). This allows the device to be used in the onstate without interference from the current limit. The device is fully protected at all drain currents, as the low power dissipation generated outside saturation makes current limit unnecessary.
9. Over-temperature protection is designed to prevent device destruction under fault conditions. Fault conditions are considered as “outside” normal operating range, so this part is not designed to withstand over-temperature for extended periods.

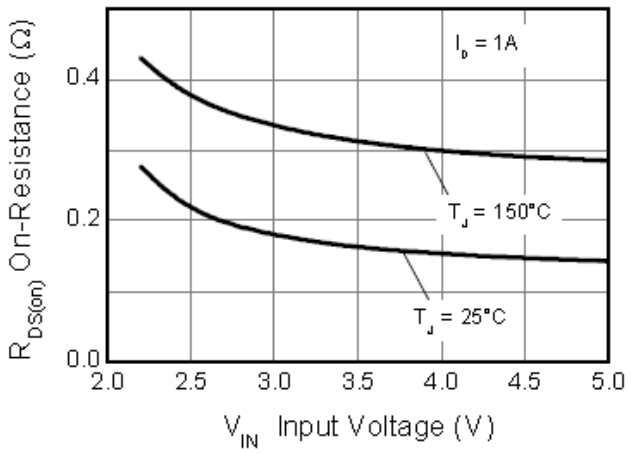
Typical Characteristics (Cont.)



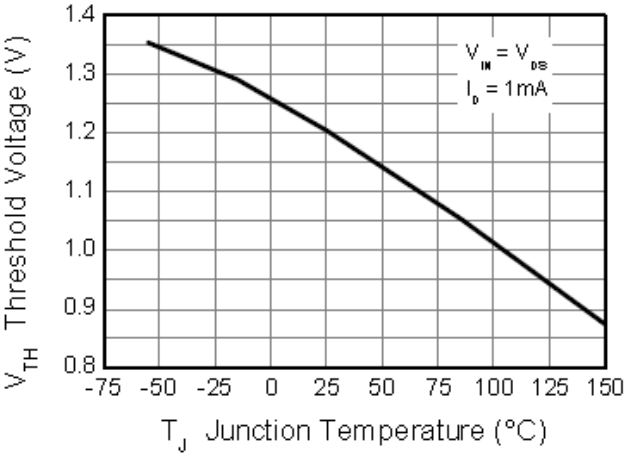
Typical Output Characteristic



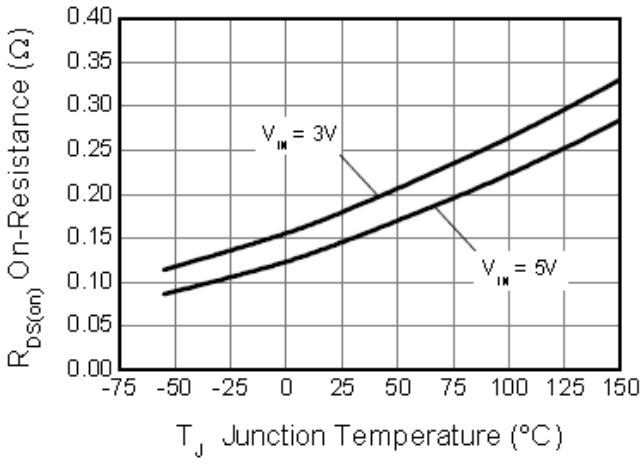
Input Current vs Input Voltage



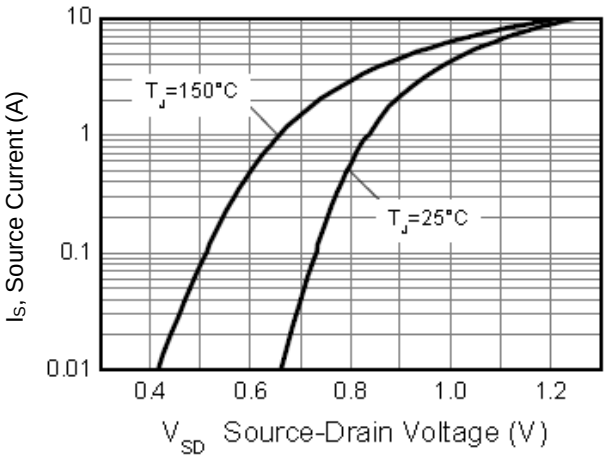
On-Resistance vs Input Voltage



Threshold Voltage vs Temperature

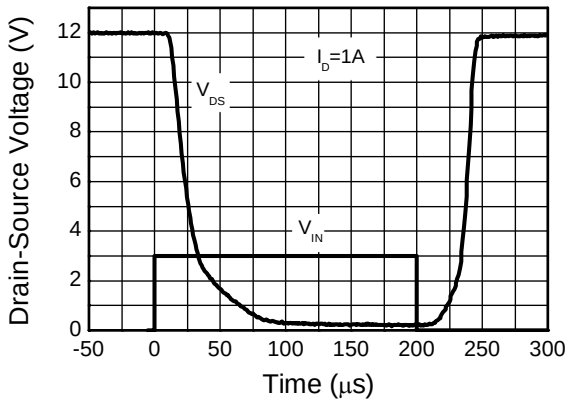


On-Resistance vs Temperature

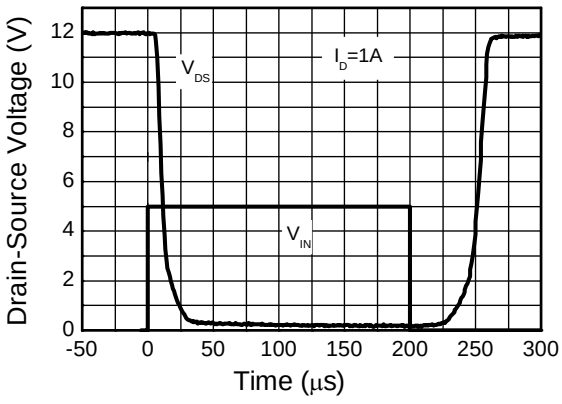


Reverse Diode Characteristic

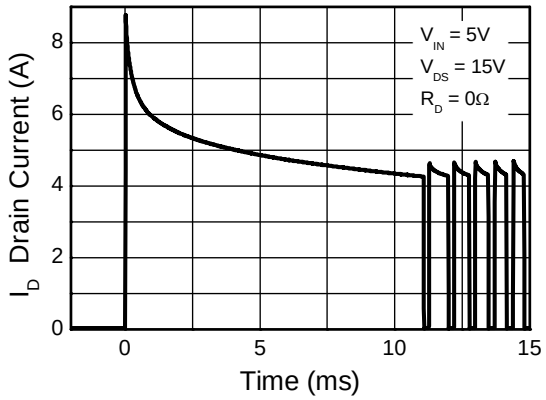
Typical Characteristics (Cont.)



Switching Speed



Switching Speed

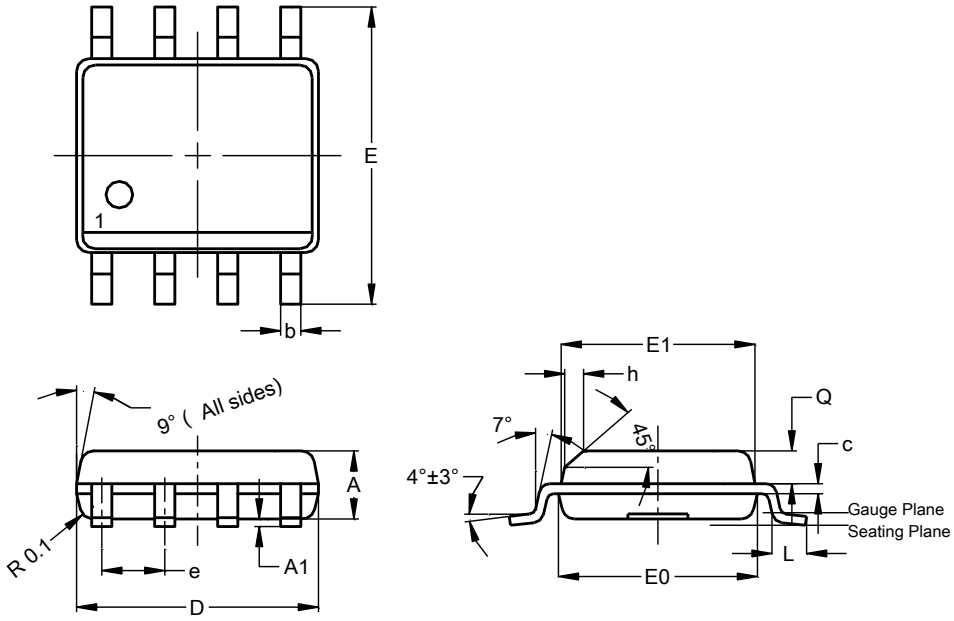


Typical Short Circuit Protection

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8

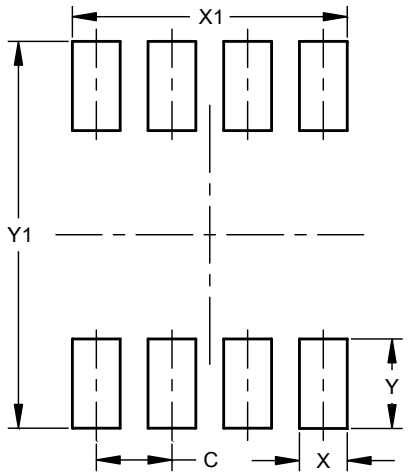


SO-8			
Dim	**Min**	**Max**	**Typ**
A	1.40	1.50	1.45
A1	0.10	0.20	0.15
b	0.30	0.50	0.40
c	0.15	0.25	0.20
D	4.85	4.95	4.90
E	5.90	6.10	6.00
E1	3.80	3.90	3.85
E0	3.85	3.95	3.90
e	--	--	1.27
h	-	--	0.35
L	0.62	0.82	0.72
Q	0.60	0.70	0.65
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8



Dimensions	Value (in mm)
C	1.27
X	0.802
X1	4.612
Y	1.505
Y1	6.50

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2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

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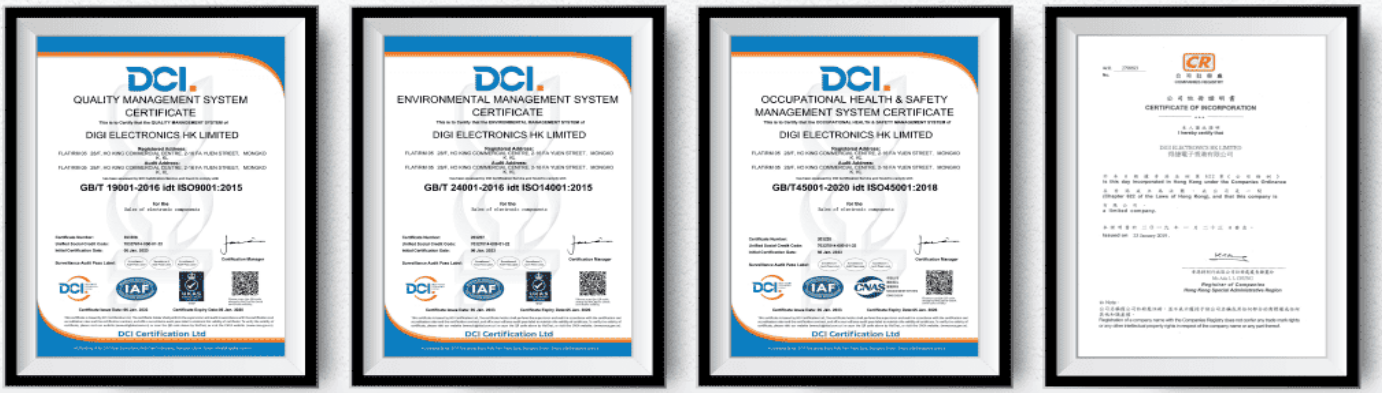

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